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# A new chemresistive NO<sub>2</sub> sensing material: Hafnium diboride

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#### ARTICLE INFO

Keywords: HfB<sub>2</sub> Metal diborides Nanoparticles NO<sub>2</sub> Gas sensing

#### ABSTRACT

While metal oxides and metal sulfides have been extensively studied for gas sensing applications, there are no extensive reports on gas sensing properties of metal diborides. Here, for the first time, we have investigated the conductometric gas sensing behavior of  $HfB_2$  nanoparticles. The  $HfB_2$  nanoparticles is synthesized via a sol-gel method and characterized using X-ray diffraction, field emission scanning electron microscopy, transmission electron microscopy, and X-ray photoelectron spectroscopy. The gas sensor is fabricated by drop casting the  $HfB_2$  nanoparticles on interdigitated Ag/Pd electrodes. The sensor exhibited a promising  $NO_2$  sensing performance at the operating temperature of 200 °C. Interestingly, it is found that resistance of the sensor decreases upon exposure to both oxidizing and reducing gases, which does not follow the gas sensing behaviors of the widely investigated metal oxides. In addition, the sensor response is minimally influenced by oxygen background concentration. These results highlight that  $HfB_2$  nanoparticles exhibit very unique sensing characteristics.

#### 1. Introduction

In 1962, Seiyama et al. proposed using the phenomenon of ZnO resistance change upon exposure to reducing gases for gas detection [1]. Since then, conductometric gas sensors have attracted great interest, have been extensively investigated and developed, and have become one of the most widely used devices for gas detection [2–4]. The basic working principle of conductometric gas sensors is based on the electrical conductivity change of the sensors upon exposure to the target gas due to the adsorption and reaction of the gas on the surface of the sensing material that is integrated into various solid-state sensors [5–7]. Thus, the properties of the gas sensing materials play a key role in determining the performance of such gas sensors, and the continued advancement of such gas sensors hinges on the development of the gas sensing materials.

Motivated by the pursuit of better sensing performance, researchers over the past few decades have extensively developed and studied various materials for conductometric gas sensing applications. These include metal oxides (e.g., ZnO,  $In_2O_3$ , WO<sub>3</sub>, NiO, CuO) [8–13], metal

sulfides (e.g., ZnS, PbS, WS<sub>2</sub>) [14–16], metal-organic-frameworks (MOFs) [17], graphene [18,19], transition metal dichalcogenides (e.g., MoS<sub>2</sub>, WSe<sub>2</sub>) [20,21], conductive polymers [22,23], and MXenes [24, 25]. However, to date, there is no experimental knowledge of the gas sensing properties of metal diborides.

Hafnium diboride (HfB<sub>2</sub>), a typical metal diboride, is known as excellent ultra-high temperature ceramic and is characterized by good chemical stability, high melting point, and high strength [26]. It also possesses other qualities such as excellent oxidization resistance, high hardness, high ablation resistance, and is electrically conductive [27]. Owing to these unique properties, HfB<sub>2</sub> has been considered as an ideal candidate for applications that involve extreme conditions, such as neutron absorber in nuclear reactors, wear-resistant coating, plasma arc electrodes, and shielding for hypersonic vehicles [28]. Recent efforts have focused on applications of HfB<sub>2</sub> in solar energy absorbers and electrocatalysts [29]. Via theoretical calculations, Xiong et al. [30] predicted the presence of Dirac cone in two-dimensional (2D) HfB<sub>2</sub>, as well as the good stability, high carrier mobility, and excellent electronic transport properties. These indicate that low-dimensional HfB<sub>2</sub> could be

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a promising material in nanoelectronics and sensing devices, especially in those expected to work in harsh environments. Although the application space of HfB<sub>2</sub> is expanding, experimental studies on its gas sensing properties have not yet been reported.

Here, we present what we believe is the first report on the conductometric gas sensing behavior of HfB2 nanoparticles. The HfB2 nanoparticles was prepared by a sol-gel route followed by high-temperature annealing processes, and the sensor was fabricated by coating the prepared HfB2 nanoparticles on an interdigitated Ag/Pd electrode. The sensor showed promising NO2 sensing properties at the operating temperature of 200 °C. The results indicate that HfB2 may provide a new choice in the material library for the fabrication of next-generation gas sensors.

### 2. Experimental

### 2.1. Material synthesis

The preparation method of  $HfB_2$  nanoparticles was detailed in our previous report [28]. Briefly, boron nanoparticles (Specialty Materials, Inc.) with an average size of 30 nm were dispersed in ethanol to form the ethanolic boron suspension. Hafnium tetrachloride (Sigma-Aldrich 98%) and deionized water with the molar ratio of  $H_2O/Hf/B = 34/1/10$  were added to the suspension and then chilled to 0 °C. The propylene oxide (Sigma-Aldrich 99%, PO) with the PO/Hf molar ratio of 9:1 was added to the mixture while stirring. Then, the wet gel was collected and washed with acetone followed by an ambient drying process. The dried gel was borothermally reduced in a graphite furnace at 1100 °C under a helium gas flow (Eq. (1)). Finally, to evaporate the remaining  $B_2O_3$  and obtain high purity  $HfB_2$ , a second annealing process was subsequently conducted at 1600 °C (Eq. (2)).

$$3HfO_2(s) + 10B(s) \rightarrow 3HfB_2(s) + 2B_2O_3(1)$$
 (1)

$$2B_2O_3(1) \rightarrow 2B_2O_3(g)$$
 (2)

### 2.2. Material characterizations

The X-Ray diffraction (XRD) pattern was recorded on a powder diffractometer (Rigaku Miniflex) with Cu  $K_{\alpha}$  radiation ( $\lambda=0.15406$  nm) for phase structure analysis. The morphology and microstructure were studied by using field emission scanning electron microscopy (FESEM, Zeiss Ultra 55) and transmission electron microscopy (TEM, JEM-2100), with the operating voltages of 5 and 200 kV, respectively. The surface chemistry and composition were investigated by X-Ray photoelectron microscopy (XPS, Thermo Scientific Escalab 250Xi) using monochromatic Al  $K_{\alpha}$  source.

### 2.3. Gas sensor fabrication and gas sensing measurements

An interdigitated Ag/Pd electrode was used as the sensing electrode in this study, shown in Fig. S1. Seven pairs of 7  $\mu m$  thick interdigitated Ag/Pd lines are deposited on a 635  $\mu m$  thick alumina substrate with width and length of 7 and 13.4  $\mu m$ , respectively. The Ag/Pd line width is 210  $\mu m$  and the spacing between two adjacent lines is 190  $\mu m$ . The prepared HfB2 nanoparticles is homogeneously dispersed in ethanol and then drop-casted on the Ag/Pd electrode using a pipette to form the sensing layer.

Fig. S2 shows the gas sensing test apparatus. The gas cylinders are individually connected to mass flow controllers (MFC, Bronkhorst) that control the mass flow rates of the gases delivered to the chamber. The target gas is diluted with pre-dried house air or  $N_2$  to obtain a specific concentration of the target gas and then delivered to the test chamber with a total flow rate of 300 sccm. All the MFCs in the gas delivery system are controlled by a LabView program. The test chamber is made out of stainless steel and is around 13 cm<sup>3</sup> in volume. The interdigitated

Ag/Pd electrode-based sensor is posited on a circular miniature heater with a diameter of 5 mm. The temperature of the heater is controlled by an external DC power supply (Sorensen, DCS2600-1.7E) and measured by a thermocouple connected to backside of the heater. The resistance of the sensor is measured using a Keithley 2602 source meter. A Java-based software suit, Zephyr, is used to record the real-time data from the gas delivery system and source meter.

The sensor response is defined as  $(R_a-R_g)/R_a$ , where  $R_a$  and  $R_g$  are the resistance of the sensor in air and in analyte gases, respectively. The response and recovery times are defined as the times for the sensor to achieve 90% of the full resistance once the target gas concentration changes, as shown in Fig. S3. The gases reported in this study include  $NO_2$  (Praxair, 21.8 ppm in  $N_2$ ), ethanol (Airgas, 978 ppm in  $N_2$ ), formaldehyde (Praxair, 22.1 ppm in  $N_2$ ), acetone (Airgas, 409 ppm in  $N_2$ ), carbon dioxide (Airgas, 20,200 ppm in  $N_2$ ) and ammonia (Praxair, 9.39 ppm in  $N_2$ ).

#### 3. Results and discussions

### 3.1. Material characterizations

XRD pattern of the prepared HfB $_2$  nanoparticles is shown in Fig. 1. The observed distinct peaks match well with the characteristic peaks of hexagonal HfB $_2$  according to ICDD PDF card #38–1398, and the three strong peaks at 25.61°, 32.89°, and 42.13° correspond to (001), (100), and (101) crystal planes, respectively. The sharp shape of these diffraction peaks indicates the high crystallinity of the prepared HfB $_2$  nanoparticles. However, two faint peaks at the 2 $\theta$  angles of around 35.00° and 38.00° are also found in the pattern, which can be ascribed to the formation of B $_4$ C (ICDD PDF card #35–0789) due to the reaction of the nanoparticles and graphite crucible during the borothermal reduction process at the relatively high temperature. Apart from these, no other peaks, such as those attributable to hafnium oxides and boron oxides, are detected.

The morphology and microstructure of the  $HfB_2$  nanoparticles are investigated by SEM and TEM. Fig. 2(a and b) show the SEM images of the prepared  $HfB_2$  nanoparticles at different magnifications. It can be seen that the nanoparticles exhibits a porous structure, composed of irregular  $HfB_2$  particles with sizes ranging from  $\sim 100$  nm to  $\sim 1$  µm. Fig. 2(c and d) show the TEM images of  $HfB_2$  nanoparticles recorded at two different positions. It can be observed that there are some small round particles with diameters of around 180 nm and some rod-like particles with larger sizes. Since there is a high-temperature sintering step in the synthesis process of  $HfB_2$  nanoparticles, some small particles

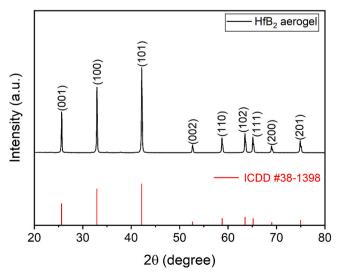


Fig. 1. XRD pattern of the prepared HfB2 nanoparticles.

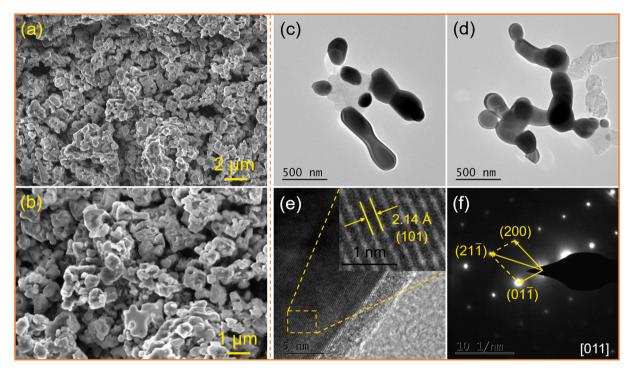


Fig. 2. (a) Low and (b) high-magnification FESEM images of HfB<sub>2</sub> nanoparticles; (c, d) TEM and (e) HRTEM images of HfB<sub>2</sub> nanoparticles, (f) the corresponding SEAD pattern.

may fuse together to form the larger particles. The HRTEM image is presented in Fig. 2(c), where the well-defined lattice fringes can be clearly observed. The measured spacing between two adjacent lines is 2.14~Å, which matches well with the d-spacing of (101) planes of

hexagonal  $HfB_2$  [31]. The corresponding SEAD pattern in Fig. 2(d) shows a clear spot array, demonstrating that the  $HfB_2$  particles are of single crystal structure.

X-ray photoelectron spectroscopy is conducted to probe the surface

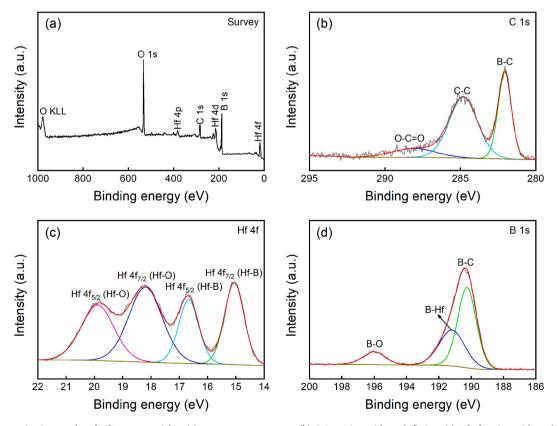


Fig. 3. XPS characterization results of HfB<sub>2</sub> nanoparticles: (a) survey scan spectrum; (b) C 1s region with peak fitting; (c) Hf 4f region with peak fitting; (d) B 1s region with peak fitting.

composition and chemical state of the prepared HfB<sub>2</sub> nanoparticles. The survey scan spectrum is shown in Fig. 3(a). In addition to the C 1s peak commonly detected due to the adventitious carbon from the contamination in air, a relatively strong O 1s peak is also observed. To further investigate the surface composition of the as-synthesized HfB2 nanoparticles, the high-resolution spectra of C 1s, Hf 4f, and B 1s regions are recorded. As can be seen in Fig. 3(b), the C 1s peak is deconvoluted into three components. The middle peak at 284.8 eV can be assigned to C-C bond, which is also used as the reference for charge calibration of all the XPS spectra [32]. The peak at lower binding energy of 282.07 eV is attributed to C-B bonding [33,34]; this reveals the existence of B<sub>4</sub>C on the surface of the prepared HfB2 nanoparticles, which is in agreement with the appearance of faith B<sub>4</sub>C peaks in the XRD pattern. The smaller peak at 288.07 eV is well accepted to correspond to the O-C=O bonding caused by adventitious carbon [35,36]. Fig. 3(c) shows the Hf 4f region of the spectrum, where two Hf bonding environments are observed. The peaks located at 15.06 and 16.67 eV are referred to  $Hf_{7/2}$  and  $Hf_{5/2}$ doublet of HfB2, respectively, while the peaks located at 18.20 and 19.89 eV are attributed to  $Hf_{7/2}$  and  $Hf_{5/2}$  of  $HfO_2$ , respectively [37]. Furthermore, the B 1s region spectrum together with the deconvoluting and fitting results are shown in Fig. 3(d) and indicate the existence of three B components. The peaks at 187.51 and 188.44 eV correspond to B-C and B-Hf bonding environments that come from B<sub>4</sub>C and HfB<sub>2</sub>, respectively [38,39]. In addition, the peak at 193.25 eV matches with the characteristic XPS peak of B-O bond [40], which may be induced by the residual B<sub>2</sub>O<sub>3</sub> in the HfB<sub>2</sub> nanoparticles. In summary, the XPS results confirm that the HfB2 has been successfully synthesized, but with the presence of HfO<sub>2</sub>, B<sub>2</sub>O<sub>3</sub>, B<sub>4</sub>C in the near surface region of the particles comprising the as-synthesized HfB2 nanoparticles. The presence of B4C can also be evidenced in the XRD result; however, no characteristic peaks of HfO2 and B2O3 can be observed in the XRD pattern, which indicates that the HfO2 and B2O3 could be amorphous in nature or crystallized but present in a relatively low amounts.

## 3.2. Gas sensing properties

Fig. 4 shows the responses and the corresponding dynamic response and recovery curves of the sensor to  $10~\rm ppm~NO_2$  at different operating

temperatures. It can be seen in Fig. 4(a) that the response decreases with increasing operating temperature, namely, a higher  $\mathrm{NO}_2$  response is observed at a lower operating temperature. However, as shown in Fig. 4 (b and c), the response times at 100 and 150 °C are rather long and the sensor cannot fully recover to its initial resistance even after 10 min. This can be due to the slow desorption rate of  $\mathrm{NO}_2$  from the surface of the HfB2 sensing layer at low operating temperatures. When the operating temperature is raised to 200 °C, the sensor shows good response and recovery characteristics to  $\mathrm{NO}_2$  and can fully recover after the  $\mathrm{NO}_2$  purge. Considering that the good reversibility, which ensures the continuous sensing capability, is one of the fundamental parameters of a gas sensor, in this study 200 °C is selected as the optimum operating temperature of the sensor for further gas sensing tests.

The transient response of the sensor to varied concentrations of NO<sub>2</sub> at the operating temperature of 200 °C is shown in Fig. 5(a). The sensor resistance drops quickly upon exposure to NO2. If the charge transfer is considered as the basic mechanism for the sensor resistance change, the result suggests that NO<sub>2</sub> molecules can trap/inject electrons from/to the HfB<sub>2</sub> during their interaction. Such a sensing behavior is similar to that of the p-type semiconducting metal oxide gas sensing materials. When turning off the NO<sub>2</sub> flow, the sensor resistance recovers to its initial value, indicating good reversibility of the HfB2 nanoparticles-based sensor. In addition, it can be seen that the resistance changes of the sensor to identical concentrations of NO<sub>2</sub> are almost the same. Namely, the sensor shows a constant response to a specific NO2 concentration. This suggests that the sensor has a good reproducibility. Furthermore, a discernible response of 1% to 0.1 ppm NO2 can be clearly observed in this figure, which indicates a low NO2 detection limit of the sensor. Closer analysis of the sensor response vs. the NO2 concentration is shown in Fig. 5(b). The sensor response increases from 1% to 28% with increasing NO<sub>2</sub> concentration from 0.1 to 10 ppm and their relationship can be fitted using the expression  $y = 9.593x^{0.475}$  (the standard errors for y and x are 0.684 and 0.038, respectively), where y is the sensor response (%) and x is the NO $_2$  concentration in ppm.

The dynamic response and recovery curves of the sensor to 10 ppm  $NO_2$  in Fig. 6(a) confirm good reversibility and reproducibility of the sensor. To further evaluate the sensor stability, the reversible  $NO_2$  sensing cycles are tested and recorded over a period of 24 days, the

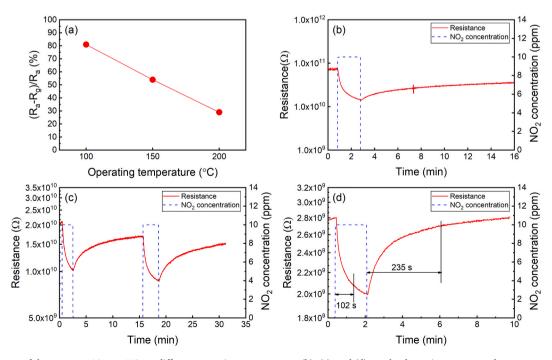


Fig. 4. (a) Responses of the sensor to 10 ppm  $NO_2$  at different operating temperatures; (b), (c), and (d) are the dynamic response and recovery curves of the sensor upon exposure to 10 ppm  $NO_2$  at the operating temperature of 100, 150, 200 °C, respectively.

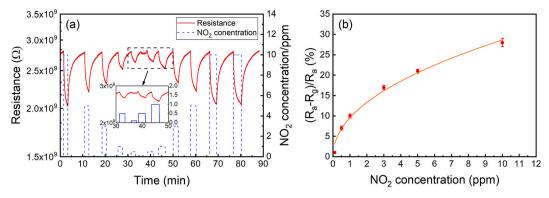


Fig. 5. (a) Dynamic response and recovery curves and (b) responses of HfB2 to different concentrations of NO2 at 200 °C.

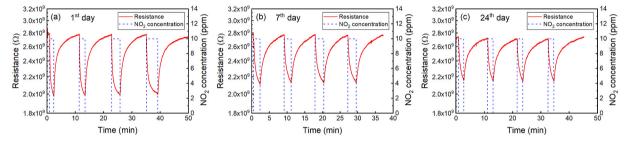


Fig. 6. Dynamic response and recovery curves to 10 ppm  $NO_2$  at the operating temperature of 200 °C. (a), (b), and (c) are the results recorded at the 1st, 7th, and 24th day of testing.

results of which are shown in Fig. 6(b and c). Comparing the data recorded at the 1st, 7th, and 24th days, the sensor shows good and consistent response and recovery characteristics over this period. The sensor response reduces from 28% to 21.5% after one week but retains this value during the rest of the examined time. Overall, the  $HfB_2$  nanoparticles-based sensor has a good stability for  $NO_2$  sensing, which is as expected due to the chemical and thermal stability of  $HfB_2$ .

The cross-sensitivity of the sensor to  $NO_2$  was assessed by separately exposing the sensor to ammonia ( $NH_3$ ), ethanol ( $C_2H_5OH$ ), formaldehyde ( $CH_2O$ ), acetone ( $C_3H_6O$ ), and carbon dioxide ( $CO_2$ ) of a comparable or higher concentration. All the tests were carried out at the operating temperature of  $200~^{\circ}C$  and the results are presented in Fig. 7.

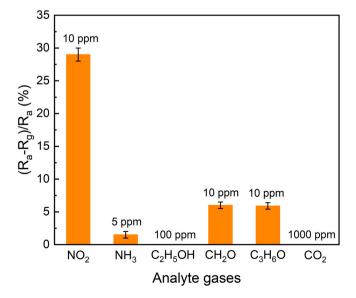


Fig. 7. Responses of  ${\rm HfB_2}$  to different gases at the operating temperature of 200  $^{\circ}{\rm C}.$ 

The sensor shows no discernible response to 100 ppm  $C_2H_5OH$  and 1000 ppm  $CO_2$ , while responses of 1.3%, 6.0%, 5.9% are observed for 5 ppm  $NH_3$ , 10 ppm  $CH_2O$ , and 10 ppm  $C_3H_6O$ , respectively, which are much lower than that to  $NO_2$  under similar concentrations, indicating a good selectivity of the sensor to  $NO_2$ .

Fig. S4 shows the dynamic response and recovery curves of the sensor to NH<sub>3</sub>, CH<sub>2</sub>O, and C<sub>3</sub>H<sub>6</sub>O. It can be seen that, similar to NO<sub>2</sub>, the sensor resistance decreases upon exposure to all these gases. This phenomenon is different from the conductometric gas sensors based on metal oxide semiconductors, for which the gas sensing mechanism generally involves the redox reaction between the test gases and the oxygen species that adsorbed on the surface of the sensing materials. Briefly, when the sensor is in air, oxygen molecules are chemisorbed on the surface of the metal oxides to form  $O_2^-$ ,  $O^-$ , and  $O^{2-}$ , depending on the temperature [41]. These adsorbed oxygen species can then react with the target gases, resulting in electron transfer between the test gas and the metal oxide gas sensing materials and, consequently, in a resistance change (sensing signal) of the sensor [42]. Under this mechanism, NO<sub>2</sub> is usually considered as an oxidizing gas while NH<sub>3</sub>, CH<sub>2</sub>O, and C<sub>3</sub>H<sub>6</sub>O are considered as reducing gases, and the resistance change of the metal oxides-based sensors follow opposite directions upon exposure to these two different types of gases. This suggests that HfB2 follows a different gas sensing mechanism from the widely investigated conductometric gas sensing materials of metal oxides. Furthermore, as discussed above, the oxygen molecules play a bridge-role in the gas sensing process of metal oxides. To provide further insight, we have compared the sensor responses towards NO2, NH3, CH2O, and C3H6O in air and in N<sub>2</sub>, as shown in Fig. S5. It is found that the sensor response to these gases in air and N2 is nearly identical. Namely, the sensor response of HfB2 is essentially independent of the oxygen molecules, which further suggests a gas sensing mechanism different from metal oxides.

As pointed out by some reports [43,44], for metal oxide semiconductors, oxygen species are mainly adsorbed on oxygen vacancies, which then react with the target gases and act as a bridge for electron transfer between the sensing materials and the target gases. This is considered the reason why metal oxide-based sensors show opposite resistance changes upon exposure to reducing and oxidizing gases and why higher responses are usually observed in materials with more oxygen vacancies [45,46]. Here, for HfB<sub>2</sub>, we speculate that the adsorption of the tested gases on the surface of the HfB2 nanoparticles is dominantly a physical process due to the lack of the surface chemisorbed oxygen, leading to the same resistance variation trend (decrease) upon exposure to all the tested gases and the observed independence on oxygen concentration. One evidence to support this conclusion is the similar resistance values of the sensor in air and in N2 (see Fig. S6), in contrast to the significant difference in baseline resistance in N2 and air observed for metal oxides due to oxygen in air trapping electrons from the conduction band of the metal oxides [47,48]. However, in order to fully understand this, much more work needs to be carried out. Nevertheless, the results show that HfB2 and potentially other transition metal diborides may provide a new material library for conductometric gas sensing applications.

#### 4. Conclusion

In this study, the gas sensing properties of HfB2 nanoparticles were investigated using an interdigitated Ag/Pd gas sensing electrode. The HfB2 nanoparticles was prepared by a sol-gel method followed by ambient drying and borothermal reduction processes. The assynthesized HfB2 nanoparticles was composed of HfB2 particles and showed a porous structure. The operating temperature of 200 °C was selected as the operating temperature of the sensor for NO<sub>2</sub> sensing, when considering both the response and response/recovery time. Under this condition, the sensor showed good reversibility, reproducibility, stability, and selectivity to NO2. Furthermore, it was observed that the sensor exhibited a reduced resistance state in response to both oxidizing and reducing gases and showed a near identical response to the tested gases in both N2 and air background. Such phenomena are distinct from those observed in studies of metal oxide gas sensing materials; thus, HfB2 may possess a different gas sensing mechanism from the metal oxides, warranting further fundamental investigation.

### Declaration of competing interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

#### Acknowledgements

The project was supported by U.S. National Science Foundation (grant # 1903188) and the Industrial Members of the Berkeley Sensor & Actuator Center. Work at the Molecular Foundry was supported by the Office of Science, Office of Basic Energy Sciences, of the U.S. Department of Energy under Contract No. DE-AC02-05CH11231. SZ, YX and ZL would like to acknowledge additional support by the China Scholarship Council.

# Appendix A. Supplementary data

Supplementary data to this article can be found online at https://doi.org/10.1016/j.ceramint.2021.11.235.

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